Solid state properties of C₆₀ and C₇₀

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Properties of C_{60} and C_{70} in the solid state, in particular, the orientational phase transitions, pressure effects, ferromagnetism in C_{60} . TDAE and interaction with metal clusters are examined.

1. INTRODUCTION

Fullerenes exhibit novel molecular properties as well as chemical reactivity. In the solid state, they exhibit interesting properties and phenomena. In this presentation, we discuss few important aspects of с₇₀. The topics solid C₆₀ and covered include phase transitions associated with orientational order. effects of pressure on the structure and electronic properties. ferromagnetism in doped C₆₀ and interaction of C₆₀ and C_{70} films with metal clusters.

2. PHASE TRANSITIONS OF C₆₀ AND C₇₀

Spherical molecules generally show orientational disorder in the solid state [1], and we would therefore expect that C₆₀ and C₇₀ show phase transitions associated with orientational order. Early structural studies on solid C₆₀ at room temperature showed that large thermal factors are necessary to obtain reasonable fits to X-ray data [2]. Based on the narrow NMR linewidths due to short orientational correlation times at room temperature, solid C_{60} was considered to be orientationally disordered [3,4]. X-ray diffraction and DSC measurements showed that C₆₀ undergoes a phase transition around 250 K on cooling from an orientationalphase to a sc ly disordered fcc phase where molecular rotation persists but only along preferred axes [5]. NMR studies show that below 250 K molecules jump between preferred orientations with a barrier of ~ 3000 K [6]. Molecular Dynamics simulation [7,8] reproduce experiobservations quite well. It mental seems necessary to add a Coulombic term to the L-J potential in order to reproduce the charge-transfer effects. Charge-transfer is also indicated by neutron diffraction measurements at 5 K [9], which show the proximity of electron-rich double bonds to adjacent electron-poor pentagonal faces.

Raman spectra of C₆₀ under pressure and related studies indioccurrence of an oriencate the C₆₀. state in tationally glassy Monte-Carlo studies [10] show that instantaneous cooling of the plastic-crystalline phase oľ C60 an orientational glassy leads to

phase with $T_g \sim 80$ K (Figure 1). Neopentane which has a plastic phase, also shows a similar behavior. A glassy state in C_{60} has been experimentally observed using dilatometry [11].



Figure 1. Density of C_{60} plotted as a function of temperature from isothermal, isobaric Monte Carlo simulations showing a transition ~ 80K.

Ellipsoidal C₇₀ shows a more complicated phase behavior that than C₆₀. Vaughan et al. [12] reported two phase transitions of C70 at 337 K and 276 K. However, the structures of these three phases are yet to be established unequivocally. At room temperature and above. both fcc and hcp structures seem to coexist as they are energetically similar. Single crystals of asgrown C₇₀ are usually twinned and unsuitable for X-ray studies. Based on X-ray studies, Verheijen et al. [13] reported the occurrence of fcc, rhombohedral. hcp2, hcp1 and distorted hcp phases on going from high to low temperatures. We have carried out powder Xstudies on C₇₀ as temperature. The ray diffraction a function of high-temperature phase is clearly

fcc and sluggishly transforms to a Thermal cycling inphase. hcp creases the crystallinity of these materials as seen from X-ray line- widths. MD simulations [14] that on cooling the highshow temperature rotator phase, a tranto a phase with trigonal sition followed symmetry occurs by a transition to a mono-clinic phase.

Phase transitions of C70 have been investigated in this laboraby both infrared [15] and tory [16] spectroscopy. IR and Raman Raman bands of sublimed C70 films línewidth absorbance and show changes across the orientational phase transitions around 340 K and 280 K (Figure 2). The phonon harden frequencies on cooling across these transitions possibly due to a combination of decreasing cell volume and increased unit intermolecular interactions. The linewidths decrease on cooling due to the hindering of the molecular resulting in a motion decrease in the rotational density of states. changes in Raman frequency The linewidth across the phase and This transitions are continuous. also appears to be true of contrary to the earlier Raman work of van Loosdrecht et al. [17]. IR evidence for the studies show coexistence of phases in the 210-Both IR and 270 K region. Raman show that orientational spectra disorder starts to freeze out below 150 K.

The effect of pressure on the phase transitions in C_{60} and C_{70} is interesting. In the case of C_{60} , the temperature of the transition at 250 K (at ambient pressure) increases at a rate of $10.3^{\circ}C$ kbar⁻¹. The DSC curve of Samara et



Figure 2 (a) Variation of the FWHM and intensity of the 643 cm⁻¹ IR band of C_{70} with temperature. (b) Variation of the 1566 cm⁻¹ Raman band FWHM and phonon frequency with temperature. Vertical arrows mark expected transition temperatures.

al. [18] shows a shoulder beyond 6 kbar indicating the presence of two nearly degenerate states near ambient pressure. **Recent measurements** al. to be published) (Ramasesha et show distinct two transitions. Raman investigations on C₆₀ single crystals under pressure [19] show that the pentagonal pinch mode undergoes considerable softening around 3.5 kbar.The linewidth increases at higher pressures till around 130 kbar (Figure 3) when the lineshape has almost merged into the background indicating an glassy orientationally state as observed by others [11].

Under pressure, C₇₀ shows three phase transitions, the highest transition temperature increasing



Figure 3 Variation of (a) the phonon frequency and (b) the linewidth of the C_{60} pentagonal pinch mode with pressure.

with pressure at a rate of 6.8°C kbar⁻¹, the lowest at 8.4°C kbar⁻¹ and the intermediate one at 5.3°C $kbar^{-1}$ (Ramasesha et al. to be published). At ambient pressure, two transitions are generally reported but the infrared studies of Varma et al. [15] indicate a plateau FWHM and peak intensities in around 330 K. A recent DSC study [20] shows however, three distinct transitions at 280, 330 and 337 K.

3. C₆₀ LUMINESCENCE UNDER PRESSURE

Early high pressure studies on C_{60} crystals from this laboratory [21] showed that the photolumines-

cence band of C₆₀ is red-shifted continuously with increasing pres-3.2 Gpa. the colour sure until at of the crystal changes from red to black. and the band disappears Since the C₆₀ ball (Figure 4). itself is largely incompressible, this closing of the PL band is interpreted as being due to a broadening of the valence and conduction band arising from increasing interball resonance. The near disappearence of the optical gap is consistent with decreasing activation energy for conduction with increasing pressure reported by a few



Figure 4 Photoluminescence band of C_{60} as a function of pressure. Inset shows variation of the optical gap with pressure.

workers. This study has certain implications for the strengths of electron-phonon coupling and therefore for superconductivity in alkali fullerides.

4. FERROMAGNETISM IN C60. TDAE

C₆₀ is an excellent electron acceptor forming radical anions. With aromatic amines, it forms weak ground state complexes and exciplexes in solution [22]. A strong amine such as TDAE (tetrakis dimethylaminoethylene) forms a radical ion salt C₆₀.TDAE is the best with C₆₀. organic ferromagnet known to date with a T_c of 16 K [23]. The lattice structure has been established by X-ray studies [24]. The cell is C60^{-C60} monoclinic with a short contact along the c-axis. ESR studies have shown that а single TDAE to electron is doped from C₆₀ [25,26]. ESR linewidth decreases with decreasing temperature indicating that C₆₀.TDAE is metallic. Single-electron doping has been by our Raman confirmed studies. by titrating the observed phonon frequencies against n [27], using the data for $C60^{n}$ from the $A_{x}C_{60}$ As with A_xC₆₀, electron phases. doping results in softening of the phonons. This phonon softening is consistent with theoretical calculations. Raman studies also show that the A_g modes of C₆₀ in C₆₀.TDAE are split due to the lower symmetry of the system. By fitting the lowtemperature susceptibility data to a series expansion for the spin-1/2, 1-D Heisenberg system [28], we have found evidence for quasi-ID behavior. The magnitude of the ferromagnetic coupling constant is 50 K. McConnell's model for ferromagnetic exchange has been used to understand this system [26,29] (Figure 5). Comparing C60. TDAE with superconduct-



Figure 5 (a) Low temperature ESR susceptibility of C_{60} .TDAE plotted against $1/T^2$. (b) Configuration Interaction (CI) picture for a ferromagnetic ground state of singly occupied ground state of 2 C_{60} species. t is the strength of the hopping integral.

ing A_3C_{60} , it would seem that the lower dimensionality and single electron doping are key features.

5. INTERACTION OF SOLID FILMS OF C₆₀ AND C₇₀ WITH TRANSITION METAL CLUSTERS

Interaction of varying coverages of transition metals such as Cu, Ni and Cr with C_{60} and C_{70} (depos-



Figure 6 UPS valence band of C_{60} with increasing Ni coverage. Inset shows change in C1s binding energy as a function of Ni coverage.

ited under UHV) have been studied by UPS and XPS [30]. The observed shifts in the valence band of C_{60}/C_{70} with increasing Ni coverage is accompanied by a shift of the C1s level of the fullerene to a lower binding energy as depicted for C_{60} in Figure 6. This suggests transfer from metal to charge fullerene, an observation of possible The in catalysis. implications

fullerenes are known to act as electron deficient π systems in solution [31].

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